





Description

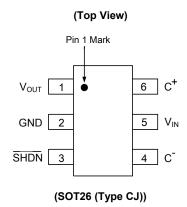
The AP3602A is a regulated step-up DC/DC converter based on charge-pump technique. The chip has the ability to supply 100mA constant-output current or 250mA peak-output current for 100ms from 3.0V to 5V input, so it can be used as a white LED driver or flash LED driver.

The AP3602A has very-low power dissipation and high efficiency in typical applications. Other features include overtemperature protection and low-temperature coefficient to meet special requirements of handheld battery-powered devices.

Only three external capacitors are required in applications, which help save space and lower cost. The chip also has a disable terminal to turn on or turn off the chip to ease the use.

The AP3602A is available in SOT26 (Type CJ) package.

Pin Assignments



Applications

- Mobile Phone Backlight Driver
- Camera Flash LED Driver
- MP3, MP4
- Handheld Device
- Portable Communication Device

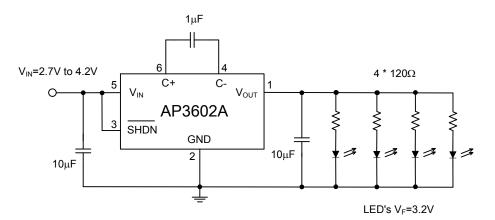
Features

- Low-Quiescent Current: 13µA Typical
- Regulated Output Voltage Precision: 4%
- **High-Output Current:**
 - 100mA when V_{IN} ≥ 3.0V
 - 50mA when V_{IN} ≥ 2.7V
- High Frequency up to 1.2MHz
- Low Shutdown Supply Current: <1µA
- High-Output Peak Current: 250mA for 100ms
- Overtemperature Protection
- Operating Temperature Range: -40°C to +85°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

Typical Applications Circuit



AP3602A Typical Application Circuit

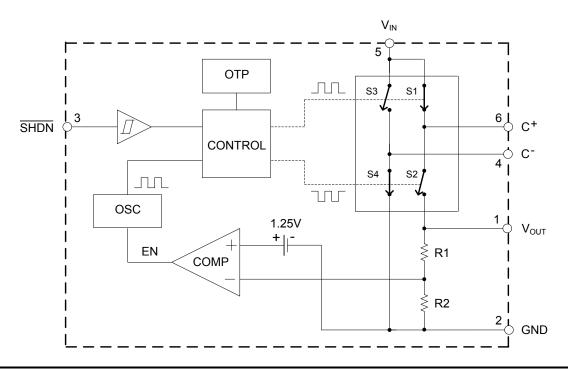


Pin Descriptions

Pin Number	Package Name	Function	
1	V _{OUT}	Regulated Output Voltage. V_{OUT} should be bypassed with a 1 μ F to 22 μ F low ESR ceramic capacitor, which is placed as close to the pin as possible for best performance	
2	GND	Ground. GND should be tied to a ground plane for best performance. The C _{OUT} and C _{IN} should be placed as close to this pin as possible	
3	SHDN	Active Low Shutdown Input. A low signal on SHDN disables the AP3602A, while a high signal enables the AP3602A. SHDN pin must not be allowed to float	
4	С	Flying Capacitor Negative Terminal. The flying capacitor should be placed as close to this pin as possible	
5	V _{IN}	Input Supply Voltage. V_{IN} should be bypassed with a $1\mu F$ to $22\mu F$ low ESR ceramic capacitor which is placed as close to the pin as possible for best performance	
6	C⁺	Flying Capacitor Positive Terminal. The flying capacitor should be placed as close to this pin as possible	



Functional Block Diagram



Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Value	Unit
V _{IN}	Input Voltage	7	V
Vo	Output Voltage	7	V
V _{SHDN}	SHDN Pin Voltage	7	V
ӨЈА	Thermal Resistance (Junction to Ambient, no Heat sink)	300	°C/W
TJ	Operating Junction Temperature	+150	°C
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _{LEAD}	Lead Temperature (Soldering, 10s)	+260	°C
_	ESD (Human Body Model)	2000	V

Note 4. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input Voltage	2.7	5	V
T _A	Operating Temperature	-40	+85	°C



$\hline \textbf{Electrical Characterist} \textbf{ics} \ (@C_{FLY} = 1 \mu F, \ C_{IN} = C_{OUT} = 10 \mu F, \ T_A = +25 ^{\circ}C, \ unless \ otherwise \ specified.) }$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V _{IN}	Input Voltage	V _O = 5V	2.7	_	Vo	V	
ΙQ	Quiescent Current	V_{IN} = 2.7V to 5.0V, I_O = 0mA, $V_{\overline{SHDN}}$ = V_{IN} , Not Switching	_	13	30	μA	
V	Outrout Valtage	2.7V < V _{IN} < 5V, I _O ≤ 50mA	4.8	5.0	5.2	V	
Vo	Output Voltage	3.0V < V _{IN} < 5V, I _O ≤ 100mA	4.8	5.0	5.2	V	
	Shutdown Supply Current	2.7V < V _{IN} < 3.6V, I _O = 0, V _{SHDN} = 0V	_	0.01	1	μΑ	
I _{SHDN}		3.6V < V _{IN} < 5.0V, I _O = 0, V _{SHDN} = 0V	_	_	2.5		
.,	Ripple Voltage	V _{IN} = 2.7V, I _O = 50mA	_	25	_	.,	
VRIPPLE		V _{IN} = 3V, I _O = 100mA	_	30	_	mV_PP	
η	Efficiency	V _{IN} = 2.7V, I _O = 50mA	_	92	_	%	
fosc	Frequency	Oscillator free running	_	1.2	_	MHz	
V _{IH}	SHDN Input Threshold High	_	1.4	_	_		
V _{IL}	SHDN Input Threshold Low	SHDN Input Threshold Low — — —		0.3	.3 V		
l _{IH}	SHDN Input Current High	t Current High V _{SHDN} = V _{IN} -1 -1 1		1			
I _{IL}	SHDN Input Current Low	V _{SHDN} = GND	-1	_	1	μA	
t _{ON}	V _{OUT} Turn-on Time	V _{IN} = 3V, I _O = 0mA	_	0.2		ms	
I _{SC}	Short-Circuit Current	$V_{IN} = 3V$, $V_O = GND$, $V_{\overline{SHDN}} = 3V$	_	300	_	mA	



Application Information

Operating Principles

The AP3602A uses a switched-capacitor charge pump to boost the input voltage to a regulated-output voltage. Regulation is achieved by sensing the chip output voltage through an internal-resistor divider network. Controlled by an internal comparator (refer to the functional block diagram), the charge-pump circuit is enabled when the divided output voltage is below a preset trip point.

The charge pump operates at 1.2MHz with 50% duty cycle. Conversion consists of a two-phase operation. In the first phase, switches S2 and S3 are opened, and S1 and S4 are closed. During this time, C_{FLY} charges to the voltage on V_{IN} , and load current is supplied by C_{OUT} . During the second phase, S2 and S3 are closed, and S1 and S4 are opened. This action connects C_{FLY} low side to V_{IN} and C_{FLY} high side to V_{OUT} then a voltage of about 2 × V_{IN} is used to charge C_{OUT} and supply the load current. For each cycle, charge is transported from V_{IN} to V_{OUT} to maintain the output voltage in its nominal value.

This process breaks when the V_{OUT} is high enough for the reason of higher input voltage or lower load then the divided voltage at the control comparator exceeds the internal trip point high level, which compels the charge-pump circuit enter to the idle mode in which the switching cycle stops (pulse skipping), and the output voltage is continually decreased because it is maintained by the discharging of C_{OUT} only. In idle mode, the feedback circuit continues sensing V_{OUT} . If the divided voltage at the control comparator drops below the preset trip point, the comparator starts the switching cycle again.

In idle mode, the AP3602A's quiescent current is about $13\mu A$. In shutdown mode, all internal circuitry is turned off, and the AP3602A draws only leakage current from V_{IN} , which is less than $1\mu A$. So, the shutdown power loss for AP3602A is very low, which is beneficial to the battery supplied systems.

Short Circuit and Thermal Protection

The AP3602A has a thermal protection and shutdown circuit that continuously monitors the IC junction temperature.

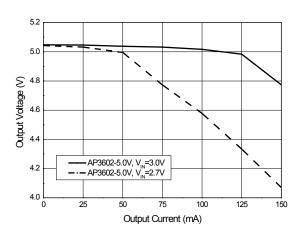
When output short-circuit occurs, the short-circuit current is about 300mA (Typical). Under this condition, the I_{IN} is about 2 × lout, which causes about 1.8W instant power dissipation on AP3602A that causes a rise in the internal IC junction temperature. If the thermal-protection circuit senses the junction temperature exceeding approximately +160°C, the thermal-shutdown circuit disables the charge-pump switching circuit. The thermal hysteresis is about +10°C, which means that the charge-pump circuit can be active when the short circuit is removed, and the junction temperature drops below +150°C.

The thermal shutdown protection cycles on and off if an output short-circuit condition persists. This allows the AP3602A to operate on a short-circuit condition without latch up or damage to the device.

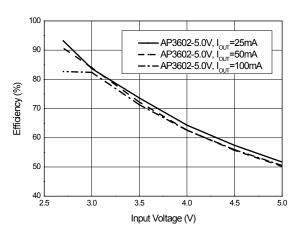


Performance Characteristics (Unless otherwise noted, V_{IN} = 3.0V, C_{IN} = C_{OUT} = 10 μ F, C_{FLY} = 1 μ F Ceramic Cap, T_A = +25°C)

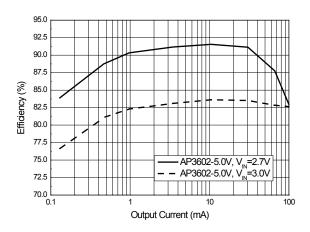
Output Voltage vs. Output Current



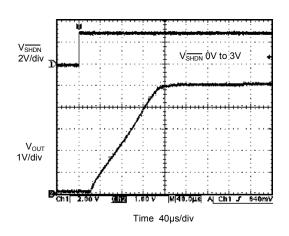
Efficiency vs. Input Voltage



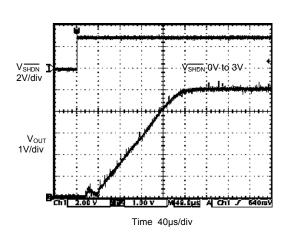
Efficiency vs. Output Current



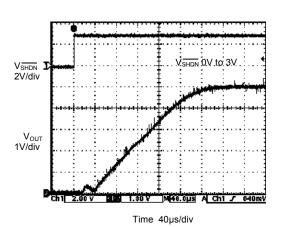
V_{OUT} Start Up Time, @ No Load



V_{OUT} Start Up Time, @50mA Load



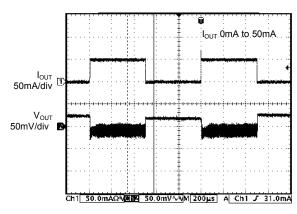
V_{OUT} Start Up Time, @100mA Load





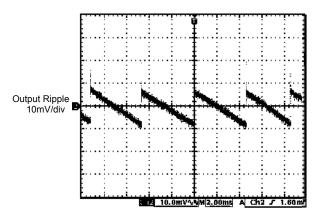
Performance Characteristics (cont.) (Unless otherwise noted, V_{IN} = 3.0V, C_{IN} = C_{OUT} = 10 μ F, C_{FLY} = 1 μ F Ceramic Cap, T_A = +25°C)

Load Transient Response



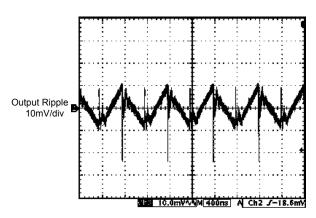
Time 200µs/div

Output Ripple @ V_{IN} = 2.7V, I_{OUT} = 0mA



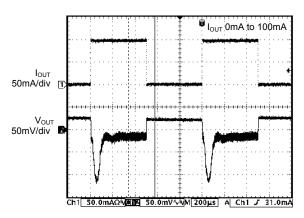
Time 2ms/div

Output Ripple @ V_{IN} = 2.7V, I_{OUT} = 100mA



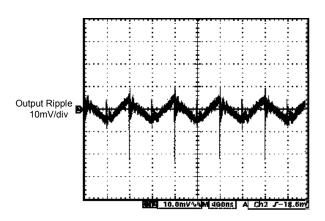
Time 400ns/div

Load Transient Response



Time 200µs/div

Output Ripple @ $V_{IN} = 2.7V$, $I_{OUT} = 50mA$

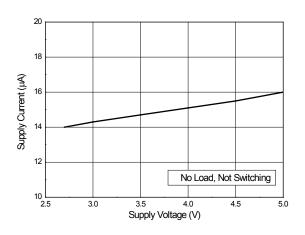


Time 400ns/div

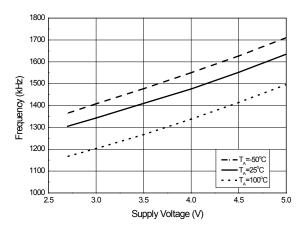


Performance Characteristics (cont.) (Unless otherwise noted, $V_{IN} = 3.0V$, $C_{IN} = C_{OUT} = 10 \mu F$, $C_{FLY} = 1 \mu F$ Ceramic Cap, $T_A = +25$ °C)

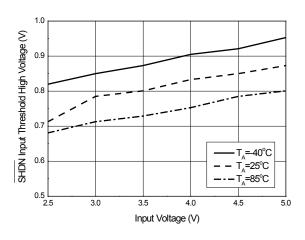
Supply Current vs. Supply Voltage



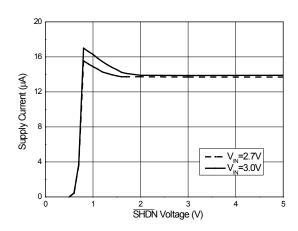
Oscillator Frequency vs. Supply Voltage



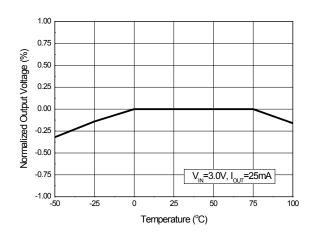
VIH VS. VIN



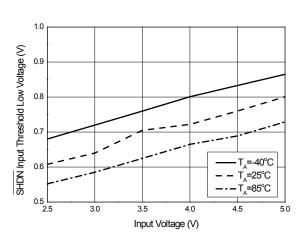
Supply Current vs. SHDN Voltage



Normalized Output Voltage vs. Temperature

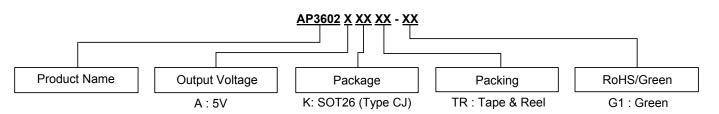


V_{IL} vs. V_{IN}





Ordering Information

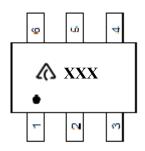


Diodes IC's Pb-free products with "G1" suffix in the part number, are RoHS compliant and green (HF).

Package	Temperature Range	Part Number	Marking ID	Packing
SOT26 (Type CJ)	-40°C to +85°C	AP3602AKTR-G1	G7T	3000/7" Tape & Reel

Marking Information

(Top View)



A: Logo

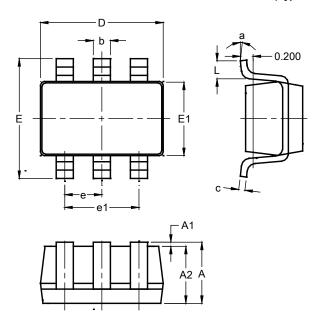
XXX: Marking ID (See Ordering Information)



Package Outline Dimensions (All dimensions in mm (inch).)

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (Type CJ)

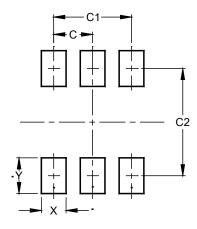


SOT26 (Type CJ)				
Dim	Min	Max	Тур	
Α	1.050	1.250		
A1	0.00	0.10		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.820	3.020	-	
Е	2.650	2.950	-	
E1	1.500	1.700	-	
е	e 0.950BSC			
e1	1.800	2.000		
L	0.300	0.600		
а	0°	8°		
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (Type CJ)



Dimensions	Value (in mm)
С	0.95
C1	1.90
C2	2.40
Х	0.60
	1.00



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